PCF2003

32 kHz watch circuit with programmable adaptive motor pulse and pulse period

Rev. 1.1 — 16 October 2019

Product data sheet

1. General description

The PCF2003 is a CMOS integrated circuit for battery operated wrist watches with a 32 kHz quartz crystal as timing element and a bipolar 1 Hz stepping motor. The quartz crystal oscillator and the frequency divider are optimized for minimum power consumption. A timing accuracy of 1 ppm is achieved with a programmable, digital frequency adjustment.

To obtain the minimum overall power consumption for the watch, an automatic motor pulse adaptation function is provided. The circuit supplies only the minimum drive current, which is necessary to ensure a correct motor step. Changing the drive current of the motor is achieved by chopping the motor pulse with a variable duty cycle. The pulse period and the range of the variable duty cycle can be programmed to suit different types of motors. The automatic pulse adaptation scheme is based on a safe dynamic detection of successful motor steps.

A pad RESET is provided (used for stopping the motor) for accurate time setting and for accelerated testing of the watch.

2. Features and benefits

- Amplitude-regulated 32 kHz quartz crystal oscillator, with excellent frequency stability and high immunity to leakage currents
- Electrically programmable time calibration with 1 ppm resolution stored in One Time Programmable (OTP) memory
- The quartz crystal is the only external component connected
- Very low supply current, typical 90 nA
- One second output pulses for bipolar stepping motor
- Five different programmable output periods (1 s to 30 s)
- Minimum power consumption for the entire watch, due to self adaptation of the motor drive according to the required torque
- Reliable step detection circuit
- Motor pulse width, pulse modulation, and pulse adaptation range programmable in a wide range, stored in OTP memory
- Stop function for accurate time setting and power saving during shelf life
- Test mode for accelerated testing of the mechanical parts of the watch and the IC
- Test bits for type recognition



32 kHz watch circuit with programmable adaptive motor pulse

3. Applications

- Driver circuits for bipolar stepping motors
- High immunity motor drive circuits

4. Ordering information

Table 1. Ordering information

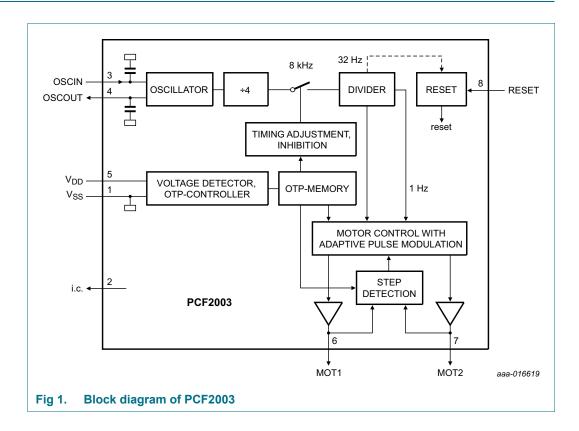
Type number	•	Package					
	marking	Name	Description	Version			
PCF2003DUS/DA	P3	WLCSP8	wafer level chip-size package; 8 bumps; 1.16 mm x 0.86 mm	PCF2003DUS			

4.1 Ordering options

Table 2. Ordering options

Type number	Orderable part number	Package	Packing method	Minimum order quantity	Temperature
PCF2003DUS/DA	PCF2003DUS/DAAZ	WLCSP8	chips with solder bumps in tape and reel, 7 inch, dry pack	4000	$T_{amb} = -10 ^{\circ}\text{C} \text{ to } +60 ^{\circ}\text{C}$

5. Block diagram

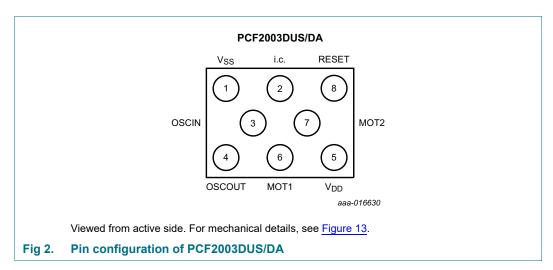


NXP Semiconductors

32 kHz watch circuit with programmable adaptive motor pulse

Pinning information

6.1 **Pinning**



6.2 Pin description

Table 3. Pin description

Input or input/output pins must always be at a defined level (VSS or VDD) unless otherwise specified.

Symbol	Pin	Description
V _{SS} [1]	1	ground
i.c.[2]	2	internally connected
OSCIN	3	oscillator input
OSCOUT	4	oscillator output
V_{DD}	5	supply voltage
MOT1	6	motor 1 output
MOT2	7	motor 2 output
RESET	8	reset input

^[1] The substrate (rear side of the chip) is connected to V_{SS} . Therefore the die pad must be either floating or connected to V_{SS}.

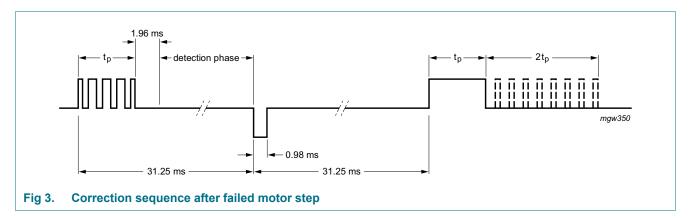
7. Functional description

7.1 Motor pulse

The motor output supplies pulses of different driving stages, depending on the torque required to turn on the motor. The number of different stages can be selected between three and six. With the exception of the highest driving stage, each motor pulse (tp in Figure 3 and Figure 6) is followed by a detection phase during which the motor movement is monitored, in order to check whether the motor has turned correctly or not.

Pad i.c. is used for factory tests; in normal operation it should be left open-circuit, and it has an internal pull-down resistance to V_{SS}.

32 kHz watch circuit with programmable adaptive motor pulse



If a missing step is detected, a correction sequence is generated (see <u>Figure 3</u>) and the driving stage is switched to the next level. The correction sequence consists of two pulses: first a short pulse in the opposite direction (0.98 ms, modulated with the maximum duty cycle) to give the motor a defined position, followed by a motor pulse of the strongest driving level. Every 4 minutes, the driving level is lowered again by one stage.

The motor pulse has a constant pulse width. The driving level is regulated by chopping the driving pulse with a variable duty cycle. The driving level starts from the programmed minimum value and increases by 6.25 % after each failed motor step. The strongest driving stage, which is not followed by a detection phase, is programmed separately.

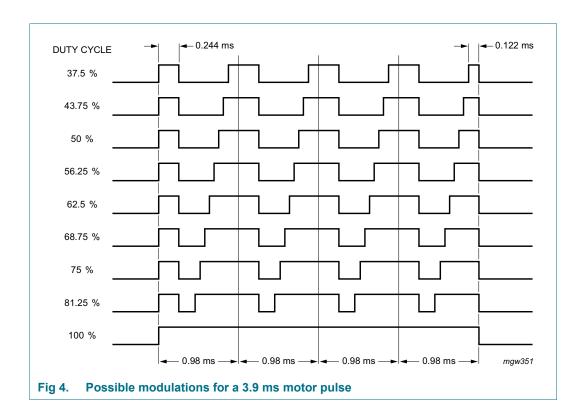
Therefore, it is possible to program a larger energy gap between the pulses with step detection and the strongest, not monitored, pulse. This might be necessary to ensure a reliable and stable operation under adverse conditions (magnetic fields and vibrations). If the watch works in the highest driving stage, the driving level jumps after the 4-minute period directly to the lowest stage, and not just one stage lower.

To optimize the performance for different motors, the following parameters can be programmed:

- Pulse width: 0.98 ms to 7.8 ms in steps of 0.98 ms
- Duty cycle of lowest driving level: 37.5 % to 56.25 % in steps of 6.25 %
- Number of driving levels (including the highest driving level): 3 to 6
- Duty cycle of the highest driving level: 75 % or 100 %
- Enlargement pulse for the highest driving level: on or off

The enlargement pulse has a duty cycle of 25 % and a pulse width which is twice the programmed motor pulse width. The repetition period for the chopping pattern is 0.98 ms. Figure 4 shows an example of a 3.9 ms pulse.

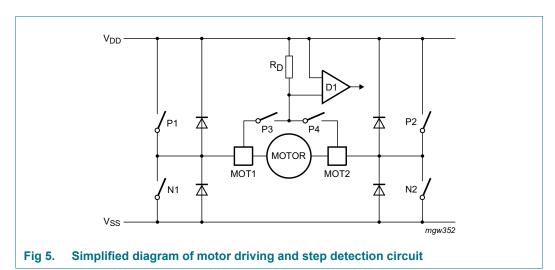
32 kHz watch circuit with programmable adaptive motor pulse



32 kHz watch circuit with programmable adaptive motor pulse

7.2 Step detection

Figure 5 shows a simplified diagram of the motor driving and step detection circuit, and Figure 6 shows the step detection sequence and corresponding sampling current. Between the motor driving pulses, the switches P1 and P2 are closed, which means the motor is short-circuited. For a pulse in one direction, P1 and N2 are open, and P2 and N1 are closed with the appropriate duty cycle; for a pulse in the opposite direction, P2 and N1 are open, and P1 and N2 closed.



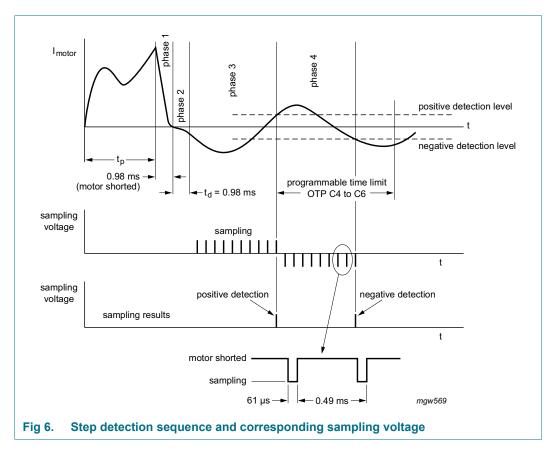
The step detection phase is initiated after the motor driving pulse. In phase 1 P1 and P2 are first closed for 0.98 ms and then in phase 2 all four drive switches (P1, N1, P2 and N2)

are opened for 0.98 ms. As a result, the energy stored in the motor inductance is reduced as fast as possible.

The induced current caused by the residual motor movement is then sampled in phase 3

The induced current caused by the residual motor movement is then sampled in phase 3 (closing P3 and P2) and in phase 4 (closing P1 and P4). For step detection in the opposite direction P1 and P4 are closed during phase 3 and P2 and P3 during phase 4 (see Figure 6).

32 kHz watch circuit with programmable adaptive motor pulse



The condition for a successful motor step is a positive step detection pulse (current in the same direction as in the driving phase) followed by a negative detection pulse within a given time limit. This time limit can be programmed between 3.9 ms and 10.7 ms (in steps of 0.98 ms) in order to ensure a safe and correct step detection under all conditions (for instance magnetic fields). The step detection phase stops after the last 31.25 ms, after the start of the motor driving pulse.

7.3 Time calibration

The quartz crystal oscillator has an integrated capacitance of 5.2 pF, which is lower than the specified capacitance (C_L) of 8.2 pF for the quartz crystal (see <u>Table 11</u>). Therefore, the oscillator frequency is typically 60 ppm higher than 32.768 kHz. This positive frequency offset is compensated by removing the appropriate number of 8192 Hz pulses in the divider chain (maximum 127 pulses), every 1 or 2 minutes. The time correction is given in <u>Table 4</u>.

Table 4. Time calibration

Calibration period	Correction per ste	p (n = 1)	Correction per step (n = 127)		
	ppm	Seconds per day	ppm	Seconds per day	
1 minute	2.03	0.176	258	22.3	
2 minutes	1.017	0.088	129	11.15	

After measuring the effective oscillator frequency, the number of correction pulses must be calculated and stored together with the calibration period in the OTP memory (see Section 7.7).

32 kHz watch circuit with programmable adaptive motor pulse

The oscillator frequency can be measured at pad RESET, where a square wave signal with the frequency of $\frac{I}{1024} \times f_{osc}$ is provided. This frequency shows a jitter every minute or every two minutes, which originates from the time calibration, depending on the programmed calibration period.

Details on how to measure the oscillator frequency and the programmed inhibition time are given in Section 7.10.

7.4 Reset

At pad RESET an output signal with a frequency of $\frac{1}{1024} \times f_{osc} = 32 \text{ Hz}$ is provided.

Connecting pad RESET to V_{DD} stops the motor drive and opens all four (P1, N1, P2 and N2) driver switches (see <u>Figure 5</u>). Connecting pad RESET to V_{SS} activates the test mode. In this mode the motor output frequency is 32 Hz, which can be used to test the mechanical function of the watch.

After releasing the pad RESET, the motor starts exactly one second later with the smallest duty cycle and with the opposite polarity to the last pulse before stopping. The debounce time for the RESET function is between 31 ms and 62 ms.

7.5 Programming possibilities

The programming data is stored in OTP cells (EPROM cells). At delivery, all memory cells are in state 0. The cells can be programmed to the state 1, but then there is no more set back to state 0. The programming data is organized in an array of four 8-bit words (see <u>Table 5</u>): word A contains the time calibration, words B and C contain the setting for the motor pulses and word D contains the type recognition.

Table 5. Words and bits

Word	Bit							
	1	2	3	4	5	6	7	8
Α	number of 81						calibration period	
В	lowest stage:	duty cycle	number of driving stages		highest stage: duty cycle	pulse stretching	output period	
С	pulse width			e delay betwee detection pulse	•	output period	factory test bit	
D	type			,	factory test bi	ts		

Table 6. Description of word A bits

Bit	Value	Description
Inhibition time		
1 to 7	-	adjust the number of the 8192 Hz pulses to be removed; bit 1 is the MSB and bit 7 is the LSB
Calibration period		
8	0	1 minute
	1	2 minutes

32 kHz watch circuit with programmable adaptive motor pulse

Table 7. Description of word B bits

Bit	Value	Description		
Duty cycle lowest	driving stage			
1 to 2	00	37.5 %		
	01	43.75 %		
	10	50 %		
	11	56.25 %		
Number of driving	stages			
3 to 4	00	3		
	01	4		
	10	5		
	11	6 <u>[1]</u>		
Duty cycle highes	t driving stage			
5	0	75 %[2]		
	1	100 %		
Pulse stretching				
6	0	no pulse stretching		
	1	pulse of 2 \timest_p and duty cycle of 25 % are added		
Output period				
7 to 8	00	1 s		
	01	5 s		
	10	10 s		
	11	20 s		

^[1] Including the highest driving stage, which one has no motor step detection.

^[2] If the maximum duty cycle of 75 % is selected, not all programming combinations are possible since the second highest level must be smaller than the highest driving level.

32 kHz watch circuit with programmable adaptive motor pulse

Table 8. Description of word C bits

Bit	Value	Description
Pulse width t _p		
1 to 3	000	0.98 ms
	001	1.95 ms
	010	2.90 ms
	011	3.90 ms
	100	4.90 ms
	101	5.90 ms
	110	6.80 ms
	111	7.80 ms
Time delay t _{d(max)}	[<u>1]</u>	
Time delay t _{d(max)} ! 4 to 6	000	3.91 ms
	001	4.88 ms
	010	5.86 ms
	011	6.84 ms
	100	7.81 ms
	101	8.79 ms
	110	9.77 ms
	111	10.74 ms
Output period		
7	0	bit 7 and 8 of word B active
	1	30 s, bit 7 and 8 of word B inactive
Factory test bit		
8	-	-

^[1] Between positive and negative detection pulses.

Byte D is read to determine which type of the PCA200x family is used in a particular application.

Table 9. Description of word D bits

Bit	Value	Description
Type recognition		
1 to 4	0000	PCA2002
	1000	PCA2000
	0100	PCA2001
	1100	PCA2003
Factory test bits		
5 to 8	-	-

32 kHz watch circuit with programmable adaptive motor pulse

7.6 Programming procedure

For a watch it is essential that the timing calibration can be made after the watch is fully assembled. In this situation, the supply pads are often the only terminals which are still accessible.

Writing to the OTP cells and performing the related functional checks is achieved in the PCF2003 by modulating the supply voltage. The necessary control circuit consists basically of a voltage level detector, an instruction counter which determines the function to be performed, and an 8-bit shift register which allows writing to the OTP cells of an 8-bit word in one step and acts as a data pointer for checking the OTP content.

There are six different instruction states (state 3 and state 5 are handled as state 4):

- State 1: measurement of the quartz crystal oscillator frequency (divided by 1024)
- State 2: measurement of the inhibition time
- State 3: write/check word A
- State 4: write/check word B
- State 5: write/check word C
- State 6: check word D (type recognition)

Each instruction state is switched on with a pulse to $V_{P(prog)(start)}$. After this large pulse, an initial waiting time of t_0 is required. The programming instructions are then entered by modulating the supply voltage with small pulses (amplitude $V_{P(mod)}$ and pulse width t_{mod}). The first small pulse defines the start time, the following pulses perform three different functions, depending on the time delay (t_d) from the preceding pulse (see Figure 7, Figure 8, Figure 11 and Figure 12):

- $t_d = t_1$ (0.7 ms); increments the instruction counter
- t_d = t₂ (1.7 ms); clocks the shift register with data = logic 0
- t_d = t₃ (2.7 ms); clocks the shift register with data = logic 1

The programming procedure requires a stable oscillator. This means that a waiting time, determined by the start-up time of the oscillator is necessary after power-on of the circuit.

After the $V_{P(prog)(start)}$ pulse, the instruction counter is in state 1 and the data shift register is cleared.

The instruction state ends with a second pulse to $V_{P(prog)(stop)}$ or with a pulse to V_{store} .

In any case, the instruction states are terminated automatically 2 seconds after the last supply modulation pulse.

7.7 Programming the memory cells

Applying the two-stage programming pulse (see <u>Figure 7</u>) transfers the stored data in the shift register to the OTP cells.

Perform the following to program a memory word:

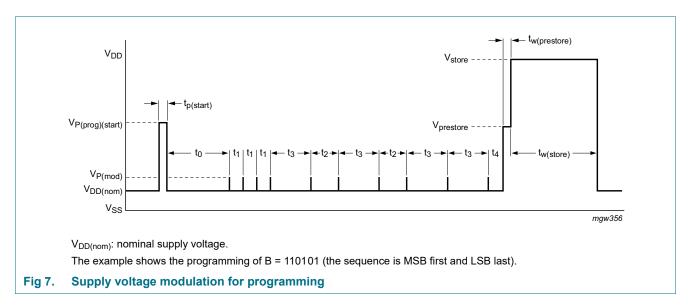
1. Starting with a $V_{P(prog)(start)}$ pulse wait for the time period t_0 then set the instruction counter to the word to be written $(t_d = t_1)$.

32 kHz watch circuit with programmable adaptive motor pulse

- Enter the data to be stored in the shift register (t_d = t₂ or t₃). LSB first (bit 8) and the MSB last (bit 1).
- 3. Applying the two-stage programming pulse V_{prestore} followed by V_{store} stores the word. The delay between the last data bit and the prestore pulse V_{prestore} is t_d = t₄. Store the word by raising the supply voltage to V_{store}; the delay between the last data bit and the store pulse is t_d.

The example shown in Figure 7 performs the following functions:

- Start
- Setting instruction counter to state 4 (word B)
- Entering data word 110101 into the shift register (sequence: LSB first and MSB last)
- Writing to the OTP cells for word B



7.8 Checking memory content

The stored data of the OTP array can be checked bit wise by measuring the supply current. The array word is selected by the instruction state and the bit is addressed by the shift register.

To read a word, the word is first selected ($t_d = t_1$), and a logic 1 is written into the first cell of the shift register ($t_d = t_3$). This logic 1 is then shifted through the entire shift register ($t_d = t_2$), so that it points with each clock pulse to the next bit.

If the addressed OTP cell contains a logic 1, a 30 k Ω resistor is connected between V_{DD} and V_{SS}, which increases the supply current accordingly.

<u>Figure 8</u> shows the supply voltage modulation for reading word B, with the corresponding supply current variation for word B = 110101 (sequence: first MSB and last LSB).

32 kHz watch circuit with programmable adaptive motor pulse

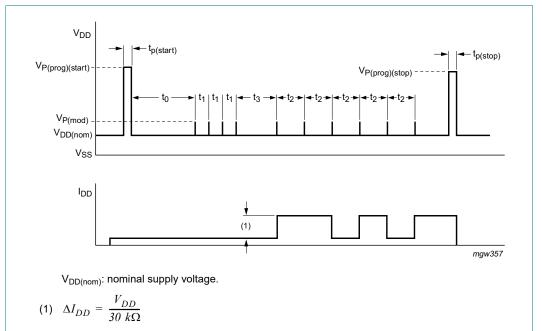
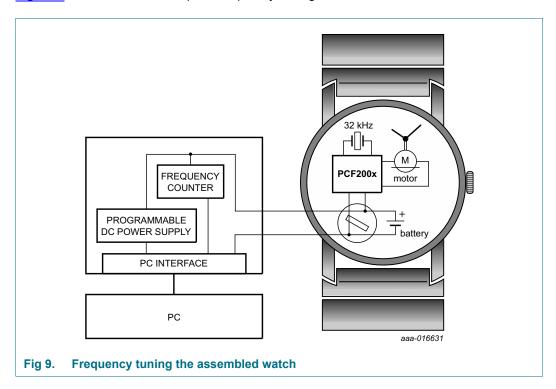


Fig 8. Supply voltage modulation and corresponding supply current variation for reading word B

32 kHz watch circuit with programmable adaptive motor pulse

7.9 Frequency tuning of assembled watch

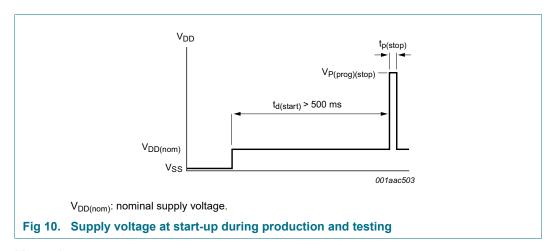
Figure 9 shows the test set-up for frequency tuning the assembled watch.



7.10 Measurement of oscillator frequency and inhibition time

The output of the two measuring states can either be monitored directly at pad RESET or as a modulation of the supply voltage (a modulating resistor of 30 k Ω is connected between V_{DD} and V_{SS} when the signal at pad RESET is at HIGH-level).

The supply voltage modulation must be followed as shown in <u>Figure 10</u> in order to guarantee the correct start-up of the circuit during production and testing.

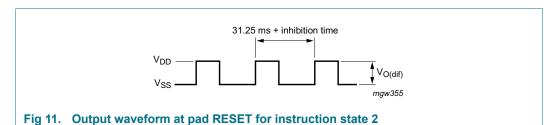


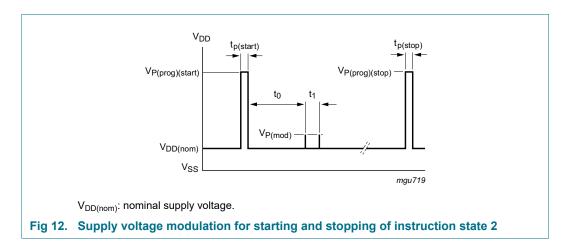
Measuring states:

Product data sheet

32 kHz watch circuit with programmable adaptive motor pulse

- State 1: quartz crystal oscillator frequency divided by 1024; state 1 starts with a pulse to V_P and ends with a second pulse to V_P
- State 2: inhibition time has a value of n × 0.122 ms. A signal with periodicity of 31.25 ms + n × 0.122 ms appears at pad RESET and as current modulation at pad V_{DD} (see <u>Figure 11</u> and <u>Figure 12</u>)





7.11 Customer testing

Connecting pad RESET to V_{SS} activates the test mode. In this test mode, the motor output frequency is 8 Hz; the duty cycle reduction and battery check occurs every second, instead of every 4 minutes.

8. Safety notes

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

CAUTION



Semiconductors are light sensitive. Exposure to light sources can cause the IC to malfunction. The IC must be protected against light. The protection must be applied to all sides of the IC.

32 kHz watch circuit with programmable adaptive motor pulse

9. Limiting values

Table 10. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DD}	supply voltage	V _{SS} = 0 V	[1][2]	-1.8	+7.0	V
VI	input voltage	on all supply pins		-0.5	+7.5	V
t _{sc}	short circuit duration time	output		-	indefinite	s
T _{amb}	ambient temperature			-10	+60	°C
V _{ESD}	electrostatic discharge	НВМ	[3]	-	±2000	V
	voltage	MM	[4]	-	±200	V
I _{lu}	latch-up current		<u>[5]</u>	-	100	mA
T _{stg}	storage temperature		<u>[6]</u>	-30	+100	°C

- [1] When writing to the OTP cells, the supply voltage (V_{DD}) can be raised to a maximum of 12 V for a time period of 1 s.
- [2] Connecting the battery with reversed polarity does not destroy the circuit, but in this condition a large current flows, which rapidly discharges the battery.
- [3] Pass level; Human Body Model (HBM), according to Ref. 6 "JESD22-A114".
- [4] Pass level; Machine Model (MM), according to Ref. 7 "JESD22-A115".
- [5] Pass level; latch-up testing according to Ref. 8 "JESD78" at maximum ambient temperature (T_{amb(max)}).
- [6] According to the store and transport requirements (see Ref. 10 "UM10569") the devices have to be stored at a temperature of +8 °C to +45 °C and a humidity of 25 % to 75 %.

32 kHz watch circuit with programmable adaptive motor pulse

10. Characteristics

Table 11. Characteristics

 V_{DD} = 1.55 V; V_{SS} = 0 V; f_{osc} = 32.768 kHz; T_{amb} = 25 °C; quartz crystal: R_S = 40 k Ω , C_1 = 2 fF to 3 fF, C_L = 8.2 pF; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply				1		
V_{DD}	supply voltage	normal operating mode; T _{amb} = -10 °C to +60 °C	1.1	1.55	3.60	V
ΔV_{DD}	supply voltage variation	ΔV/Δt = 1 V/μs	-	-	0.25	V
I _{DD}	supply current	between motor pulses	-	90	120	nA
		between motor pulses at V _{DD} = 3.5 V	-	120	180	nA
		T _{amb} = -10 °C to +60 °C	-	-	200	nA
		stop mode; pad RESET connected to V _{DD}	-	100	135	nA
Motor out	put					
V_{sat}	saturation voltage	$R_{motor} = 2 \text{ k}\Omega;$ $T_{amb} = -10 \text{ °C to +60 °C}$	[1] -	150	200	mV
$Z_{o(sc)}$	output impedance (short circuit)	between motor pulses; I _{motor} < 1 mA	-	200	300	Ω
Oscillator			-	<u> </u>		
V _{start}	start voltage		1.1	-	-	V
g _m	transconductance	$V_{i(osc)} \le 50 \text{ mV (p-p)}$	5	10	-	μS
t _{startup}	start-up time		-	0.3	0.9	s
Δf/f	frequency stability	$\Delta V_{DD} = 100 \text{ mV}$	-	0.05	0.20	ppm
C _{L(itg)}	integrated load capacitance		4.3	5.2	6.3	pF
R _{par}	parasitic resistance	allowed resistance between adjacent pads	20	-	-	ΜΩ
Pad RESE	т	1	l .		l .	ı
f _o	output frequency		-	32	-	Hz
$V_{O(dif)}$	differential output voltage	$R_L = 1 \text{ M}\Omega; C_L = 10 \text{ pF}$	2 1.4	-	-	V
t _r	rise time	$R_L = 1 \text{ M}\Omega; C_L = 10 \text{ pF}$	[2] _	1	-	μs
t _f	fall time	$R_L = 1 \text{ M}\Omega; C_L = 10 \text{ pF}$	[2] _	1	-	μs
I _{i(AV)}	average input current	pad RESET connected to V _{DD} or V _{SS}	-	10	20	nA

^[1] P1 + ... + P4 + N1 + N2 (see Section 7.2).

^[2] R_L and C_L are a load resistor and load capacitor, externally connected to pad RESET.

32 kHz watch circuit with programmable adaptive motor pulse

11. OTP programming characteristics

Table 12. Specifications for OTP programming

See Figure 7, Figure 8 and Figure 12.

Symbol	Parameter ^[1]	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage	during programming procedure	1.5	-	3.0	V
V _{P(prog)(start)}	programming supply voltage (start)		6.6	-	6.8	V
V _{P(prog)(stop)}	programming supply voltage (stop)		6.2	-	6.4	V
$V_{P(mod)}$	supply voltage modulation	for entering instructions, referred to V_{DD}	320	350	380	mV
V _{prestore}	prestore voltage	for prestore pulse	6.2	-	6.4	V
V _{store}	store voltage	for writing to the OTP cells	9.9	10.0	10.1	V
I _{store}	store current	for writing to the OTP cells	-	-	10	mA
t _{p(start)}	start pulse width		8	10	12	ms
t _{p(stop)}	pulse width of stop pulse		0.05	-	0.5	ms
t _{mod}	modulation pulse width		25	30	40	μS
t _{w(prestore)}	prestore pulse width		0.05	-	0.5	ms
t _{w(store)}	store pulse width	for writing to the OTP cells	95	100	110	ms
t ₀	time 0	waiting time after start pulse	20	-	30	ms
t ₁	time 1	pulse distance for incrementing the state counter	0.6	0.7	8.0	ms
t ₂	time 2	pulse distance for clocking the data register with data = logic 0	1.6	1.7	1.8	ms
t ₃	time 3	pulse distance for clocking the data register with data = logic 1	2.6	2.7	2.8	ms
t ₄	time 4	waiting time for writing to OTP cells	0.1	0.2	0.3	ms
SR	slew rate	for modulation of the supply voltage	0.5	-	5.0	V/µs
R _{mod}	modulation resistance	supply current modulation read-out resistor	18	30	45	kΩ

^[1] Program each word once only.

32 kHz watch circuit with programmable adaptive motor pulse

12. Bare die outline

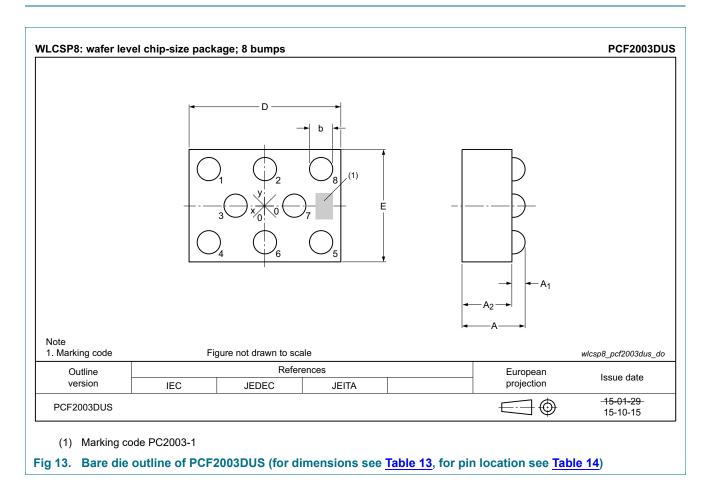


Table 13. Dimension of PCF2003US

Original dimensions are in mm.

Unit (mm)	Α	A ₁	A ₂	b	D	E
max	-	-	-	-	1.19	0.89
nom	0.53	0.15	0.38	0.20	1.16	0.86
min	-	-	-	-	1.13	0.83

32 kHz watch circuit with programmable adaptive motor pulse

Table 14. Bonding pad description

Symbol	Pin	X[1]	Y[1]	Туре	Description
V _{SS} [2]	1	-430	280	supply	ground
i.c.[3]	2	0	280	-	internally connected
OSCIN	3	-225	0	input	oscillator input
OSCOUT	4	-430	-280	output	oscillator output
V_{DD}	5	430	-280	supply	supply voltage
MOT1	6	0	-280	output	motor 1 output
MOT2	7	225	0	output	motor 2 output
RESET	8	430	280	input	reset input

- [1] All coordinates are referenced, in μm , to the center of the die (see Figure 13).
- [2] The substrate (rear side of the chip) is connected to V_{SS}. Therefore the die pad must be either floating or connected to V_{SS}.
- [3] Pad i.c. is used for factory tests; in normal operation it should be left open-circuit, and it has an internal pull-down resistance to V_{SS}.

13. Handling information

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling Metal-Oxide Semiconductor (MOS) devices ensure that all normal precautions are taken as described in *JESD625-A*, *IEC 61340-5* or equivalent standards.

32 kHz watch circuit with programmable adaptive motor pulse

14. Packing information

14.1 Tape and reel information

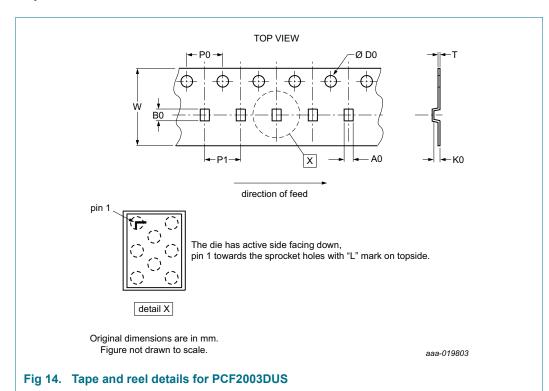


Table 15. Carrier tape dimensions of PCF2003DUS

Nominal values with production tolerances.

Symbol	Description	Value	Unit	
Compartments				
A0	pocket width in x direction	1.00 ± 0.05	mm	
B0	pocket width in y direction	1.30 ± 0.05	mm	
K0	pocket depth	0.62 ± 0.05	mm	
Overall dime	nsions	,		
W	tape width	8	mm	
Т	tape thickness	0.2 ± 0.02	mm	
D0	sprocket hole diameter	1.5	mm	
P0	sprocket hole pitch	4 ± 0.1	mm	
P1	pocket pitch	4 ± 0.1	mm	

32 kHz watch circuit with programmable adaptive motor pulse

15. Soldering of WLCSP packages

15.1 Introduction to soldering WLCSP packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering WLCSP (Wafer Level Chip-Size Packages) can be found in application note AN10439 "Wafer Level Chip Scale Package" and in application note AN10365 "Surface mount reflow soldering description".

Wave soldering is not suitable for this package.

All NXP WLCSP packages are lead-free.

15.2 Board mounting

Board mounting of a WLCSP requires several steps:

- 1. Solder paste printing on the PCB
- 2. Component placement with a pick and place machine
- 3. The reflow soldering itself

15.3 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 15</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues, such as smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature), and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic) while being low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 16.

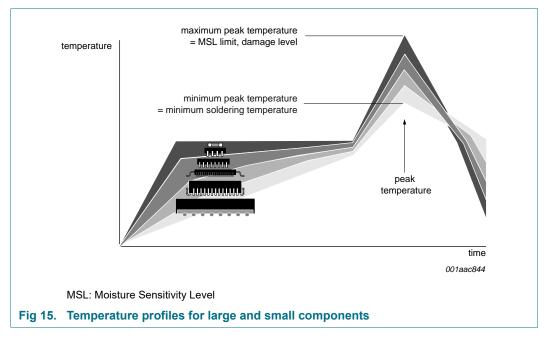
Table 16. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C) Volume (mm³)			
	< 350	350 to 2000	> 2000	
< 1.6	260	260	260	
1.6 to 2.5	260	250	245	
> 2.5	250	245	245	

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 15.

32 kHz watch circuit with programmable adaptive motor pulse



For further information on temperature profiles, refer to application note *AN10365* "Surface mount reflow soldering description".

15.3.1 Stand off

The stand off between the substrate and the chip is determined by:

- The amount of printed solder on the substrate
- The size of the solder land on the substrate
- The bump height on the chip

The higher the stand off, the better the stresses are released due to TEC (Thermal Expansion Coefficient) differences between substrate and chip.

15.3.2 Quality of solder joint

A flip-chip joint is considered to be a good joint when the entire solder land has been wetted by the solder from the bump. The surface of the joint should be smooth and the shape symmetrical. The soldered joints on a chip should be uniform. Voids in the bumps after reflow can occur during the reflow process in bumps with high ratio of bump diameter to bump height, i.e. low bumps with large diameter. No failures have been found to be related to these voids. Solder joint inspection after reflow can be done with X-ray to monitor defects such as bridging, open circuits and voids.

15.3.3 Rework

In general, rework is not recommended. By rework we mean the process of removing the chip from the substrate and replacing it with a new chip. If a chip is removed from the substrate, most solder balls of the chip will be damaged. In that case it is recommended not to re-use the chip again.

NXP Semiconductors

32 kHz watch circuit with programmable adaptive motor pulse

Device removal can be done when the substrate is heated until it is certain that all solder joints are molten. The chip can then be carefully removed from the substrate without damaging the tracks and solder lands on the substrate. Removing the device must be done using plastic tweezers, because metal tweezers can damage the silicon. The surface of the substrate should be carefully cleaned and all solder and flux residues and/or underfill removed. When a new chip is placed on the substrate, use the flux process instead of solder on the solder lands. Apply flux on the bumps at the chip side as well as on the solder pads on the substrate. Place and align the new chip while viewing with a microscope. To reflow the solder, use the solder profile shown in application note AN10365 "Surface mount reflow soldering description".

15.3.4 Cleaning

Cleaning can be done after reflow soldering.

16. Abbreviations

Table 17. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
НВМ	Human Body Model
LSB	Least Significant Bit
MM	Machine Model
MSB	Most Significant Bit
OTP	One Time Programmable

17. References

- [1] AN10365 Surface mount reflow soldering description
- [2] AN10439 — Wafer Level Chip Size Package
- AN10706 Handling bare die [3]
- [4] **IEC 60134** — Rating systems for electronic tubes and valves and analogous semiconductor devices
- **IEC 61340-5** Protection of electronic devices from electrostatic phenomena [5]
- JESD22-A114 Electrostatic Discharge (ESD) Sensitivity Testing Human Body [6] Model (HBM)
- JESD22-A115 Electrostatic Discharge (ESD) Sensitivity Testing Machine Model [7] (MM)
- [8] JESD78 — IC Latch-Up Test
- JESD625-A Requirements for Handling Electrostatic-Discharge-Sensitive [9] (ESDS) Devices
- [10] UM10569 Store and transport requirements

32 kHz watch circuit with programmable adaptive motor pulse

18. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PCF2003 v.1.1	20191016	Product data sheet	2019100081	PCF2003 v.1
Modifications:	Topside marking changed from blank to "P3" for new manufacturing flow			
PCF2003 v.1	20151020	Product data sheet	-	-

32 kHz watch circuit with programmable adaptive motor pulse

19. Legal information

19.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

19.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

19.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

PCF2003

NXP Semiconductors

32 kHz watch circuit with programmable adaptive motor pulse

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Bare die — All die are tested on compliance with their related technical specifications as stated in this data sheet up to the point of wafer sawing and are handled in accordance with the NXP Semiconductors storage and transportation conditions. If there are data sheet limits not guaranteed, these will be separately indicated in the data sheet. There are no post-packing tests performed on individual die or wafers.

NXP Semiconductors has no control of third party procedures in the sawing, handling, packing or assembly of the die. Accordingly, NXP Semiconductors assumes no liability for device functionality or performance of the die or systems after third party sawing, handling, packing or assembly of the die. It is the responsibility of the customer to test and qualify their application in which the die is used.

All die sales are conditioned upon and subject to the customer entering into a written die sale agreement with NXP Semiconductors through its legal department.

Trademarks 19.4

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

20. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

19.3 19.4 **20 21**

32 kHz watch circuit with programmable adaptive motor pulse

21. Contents

1	General description
2	Features and benefits
3	Applications
4	Ordering information 2
4.1	Ordering options
5	Block diagram 2
6	Pinning information 3
6.1	Pinning
6.2	Pin description
7	Functional description 3
7.1	Motor pulse
7.2	Step detection 6
7.3	Time calibration
7.4	Reset
7.5	Programming possibilities 8
7.6	Programming procedure
7.7	Programming the memory cells 11
7.8	Checking memory content
7.9	Frequency tuning of assembled watch 14
7.10	Measurement of oscillator frequency and
	inhibition time
7.11	Customer testing
8	Safety notes
•	oalety notes
9	Limiting values
-	Limiting values
9	Limiting values
9 10	Limiting values
9 10 11	Limiting values.16Characteristics.17OTP programming characteristics.18Bare die outline.19
9 10 11 12	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20
9 10 11 12 13	Limiting values.16Characteristics.17OTP programming characteristics.18Bare die outline.19
9 10 11 12 13 14	Limiting values 16 Characteristics 17 OTP programming characteristics 18 Bare die outline 19 Handling information 20 Packing information 21 Tape and reel information 21
9 10 11 12 13 14 14.1	Limiting values 16 Characteristics 17 OTP programming characteristics 18 Bare die outline 19 Handling information 20 Packing information 21 Tape and reel information 21 Soldering of WLCSP packages 22
9 10 11 12 13 14 14.1	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information 21 Tape and reel information. 21 Soldering of WLCSP packages. 22
9 10 11 12 13 14 14.1 15	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22
9 10 11 12 13 14 14.1 15 15.1 15.2	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22
9 10 11 12 13 14 14.1 15 15.1 15.2 15.3	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22
9 10 11 12 13 14 14.1 15.1 15.2 15.3 15.3.1	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23 Rework. 23
9 10 11 12 13 14 14.1 15 15.1 15.2 15.3 15.3.1 15.3.2	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23
9 10 11 12 13 14 14.1 15 15.1 15.2 15.3 15.3.1 15.3.2 15.3.3	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23 Rework. 23
9 10 11 12 13 14 14.1 15 15.1 15.2 15.3 15.3.1 15.3.2 15.3.3 15.3.4	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23 Rework. 23 Cleaning. 24
9 10 11 12 13 14 14.1 15 15.1 15.2 15.3 15.3.1 15.3.2 15.3.3 15.3.4	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23 Rework. 23 Cleaning. 24 Abbreviations. 24
9 10 11 12 13 14 14.1 15.1 15.2 15.3 15.3.1 15.3.2 15.3.3 15.3.4 16 17 18	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23 Rework. 23 Cleaning. 24 Abbreviations. 24 References. 24 Revision history. 25
9 10 11 12 13 14 14.1 15.1 15.2 15.3 15.3.1 15.3.2 15.3.3 15.3.4 16 17	Limiting values. 16 Characteristics. 17 OTP programming characteristics. 18 Bare die outline. 19 Handling information. 20 Packing information. 21 Tape and reel information. 21 Soldering of WLCSP packages. 22 Introduction to soldering WLCSP packages. 22 Board mounting. 22 Reflow soldering. 22 Stand off. 23 Quality of solder joint. 23 Rework. 23 Cleaning. 24 Abbreviations. 24 References. 24 Revision history. 25

Contact information	 21
Trademarks	
Disclaimers	 26

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.